

**2008 VISVESVARAYA TECHNOLOGICAL UNIVERSITY**  
**B.E/B.TECH II I SEMESTER DEGREE EXAMINATION**  
**ELECTRONICS AND COMMUNICATION ENGINEERING**  
**ANALOG ELECTRONIC CIRCUIT**

TIME 3 HOUR  
MARK 80

ANSWER ANY ALL QUESTION

**MARK [16\*5=80]**

1. a. Explain low frequency response of BJT amplifier and give expression for lower cut-off frequency due to  $C_Q$ ,  $C_E$  and  $C_s$ .  
b. Obtain expression for miller effect input and miller effect output capacitance. (10 Marks)
2. a. With necessary equivalent diagram obtain the expression for  $Z_{in}$ ,  $A_v$ ,  $Z_O$  for a Darlington Emitter follower.  
b. What are the effects of negative feedback?  
c. Obtain expression for  $Z_m$ ,  $Z_O$  for a voltage - series feedback.
3. a. What are the classification of Power Amplifiers based on the location of Q-pt? Also indicate the operating cycle in each case.  
b. Prove that the maximum conversion efficiency in class-B power amplifier is 78.5%.  
c. A power amplifier has harmonic distortions  $D_2 = 0.15$ ,  $D_3 = 0.02$ ,  $D_4 = 0.01$ , the fundamental current  $I_L = 4A$  and  $R_L = 80\Omega$ . Calculate the total harmonic distortion, fundamental power and total power.
4. a. Explain characteristics of a quartz crystal. With a neat diagram explain the crystal oscillator in Parallel - resonant circuits.  
b. Explain how a feedback circuit can be used as oscillator.  
c. Calculate operating frequency of a BJT phase - Shift oscillator for  $R = 6k\Omega$ ,  $C = 1500pF$ ,  $R_e = 18k\Omega$ . Determine minimum current gain of transistor required for sustained oscillations.
5. a. Define transconductance  $g_m$ . Derive expression for  $g_m$ .  
b. A JFET has  $g_m = 6mS$  at  $V_{GS} = -4V$ . Find  $V_{DSS}$  if pinch off voltage  $V_P = -2.5V$ .  
c. With necessary equivalent circuit obtain the expression for  $A_v$ ,  $Z_m$ ,  $Z_O$  for a fixed-biased JFET Amplifier.